LED910D-01

Rev. A1



- Infrared LED
- 910 nm, 13 mW
- Chip: AlGaAs, 350 x 350 μm, 1 pc.
- 5 mm Clear Molding, Epoxy Resin
- Viewing Angle: 22°





Description

LED910D-01 contains one AlGaAs LED chip die with a typical peak wavelength of **910 nm** and radiation power of **13 mW**. It comes in Ø5 mm clear molding package with soldered lead frame (lead free) and lens molded with epoxy resin.

Maximum Ratings (TCASE=25°C)

5		Val	11.24	
Parameter	Symbol	Min.	Max.	Unit
Power Dissipation	P_D		200	mW
Forward Current	IF		100	mA
Pulse Forward Current *1	I _{FP}		1000	mA
Reverse Voltage	VF		5	V
Thermal Resistance	R_{THJA}		250	K/W
Junction Temperature	T_J		120	°C
Operating Temperature	T_{CASE}	- 40	+ 100	°C
Storage Temperature	T_{STG}	- 40	+ 100	°C
Lead Solder Temperature *2	T_{SLD}		+ 265	°C

^{*1} duty=1%, pulse width = 10 µs

Electro-Optical Characteristics (TCASE=25°C)

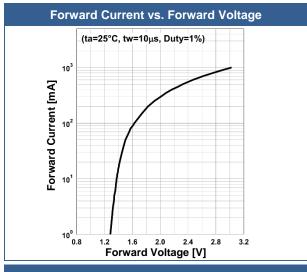
Parameter	Symbol	Conditions	Min.	Values Typ.	Max.	Unit
Peak Wavelength	λ_P	I _F =50mA	900		920	nm
Half Width	$\Delta \lambda$	I _F =50mA		35		nm
Forward Voltage	VF	I _F =50mA		1.5	(2.0)	V
Forward Voltage	V_{FP}	I _{FP} =1A		3.0		
Radiated Power *1	ρ.	I _F =50mA		13		mW
Radiated Power	Po	I _{FP} =1A		210		
Dadient Intensity *?	,_	I _F =50mA		50		mW/sr
Radiant Intensity *2	ΙE	I _{FP} =1A		810		mvv/sr
Viewing Angle	2θ1/2	I _F =50mA		22		deg.
Rise Time	t r	I _F =50mA		50		ns
Fall Time	t f	I _F =50mA		50		ns

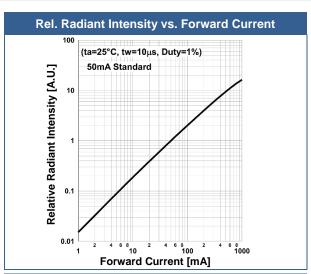
^{*1} measured by S3584-08

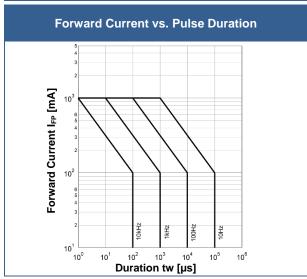
^{*2} must be completed within 5 seconds

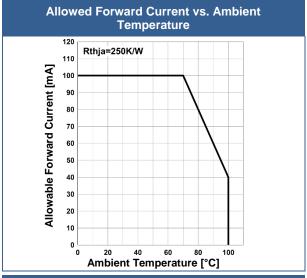
^{*2} measured by CIE127-2007 Condition B

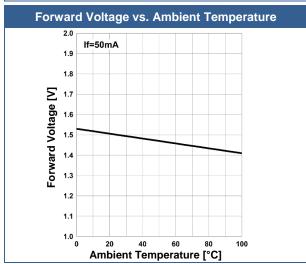
Typical Performance Curves

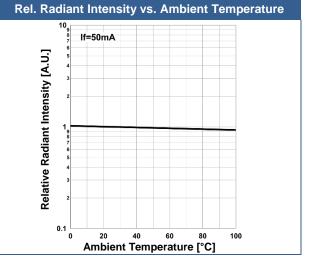










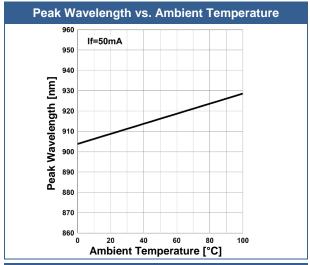


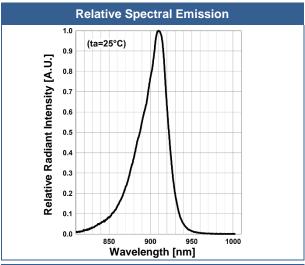


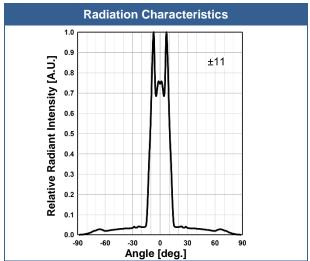
ROITHNER LASERTECHNIK GmbH

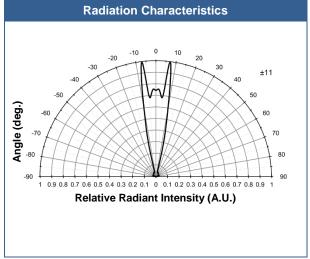
WIEDNER HAUPTSTRASSE 76 IO40 VIENNA AUSTRIA TEL. +43 I 586 52 43 -0, FAX. -44 OFFICE@ROITHNER-LASER.COM



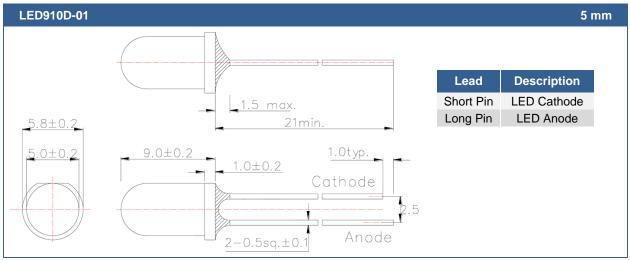








Outline Dimensions



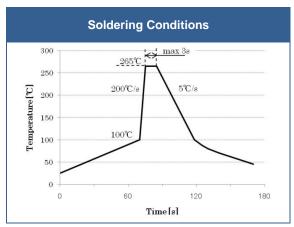
All Dimensions in mm

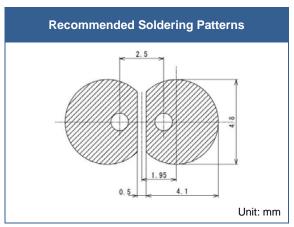
Precautions

Soldering:

- Do avoid overheating of the LED
- Do avoid electrostatic discharge (ESD)
- · Do avoid mechanical stress, shock, and vibration
- Do only use non-corrosive flux
- Do not apply current to the LED until it has cooled down to room temperature after soldering

Recommended soldering conditions:





Above table specifies the maximum allowed duration and temperature during soldering. It is strongly advised to perform soldering at the shortest time and lowest temperature possible.

Cleaning:

Cleaning with isopropyl alcohol, propanol, or ethyl alcohol is recommended

DO NOT USE acetone, chloroseen, trichloroethylene, or MKS

DO NOT USE ultrasonic cleaners

Static Electricity:

LEDs are sensitive to electrostatic discharge (ESD). Precautions against ESD must be taken when handling or operating these LEDs. Surge voltage or electrostatic discharge can result in complete failure of the device.

Radiation:

During operation these LEDs do emit light, which could be hazardous to skin and eyes, and may cause cancer. Do avoid exposure to the emitted light. Protective glasses if needed. It is further advised to attach a warning label on products/systems.

Operation:

Do only operate LEDs with a current source.

Running these LEDs from a voltage source will result in complete failure of the device.

Current of a LED is an exponential function of the voltage across it. Usage of current regulated drive circuits is mandatory.

Revisions History

Rel.	Rel. Date	Chapter	Modification	Page
A1	2010-09-02	-	Initial release	-

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The above specifications are for reference purpose only and subjected to change without prior notice